

Supporting Information

Bilayer Quantum Dot-decorated Mesoscopic Inverse Opals for High Volumetric Photoelectrochemical Water Splitting Efficiency

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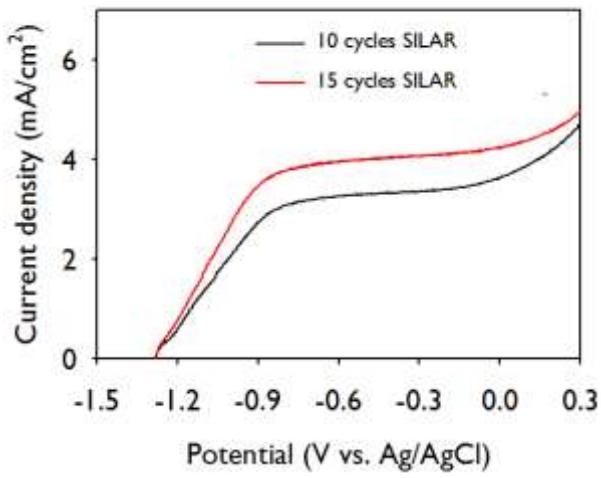


Fig. S1. Current-voltage curves of the CdS meso-IO TiO₂ with various thickness of CdS layer under the illumination of the AM1.5G solar light.

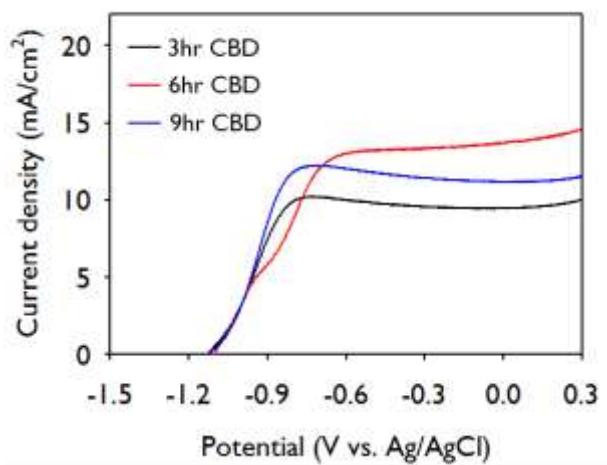


Fig. S2. Current-voltage curves of the CdSe/CdS meso-IO TiO₂ with various thickness of CdSe layer under the illumination of the AM1.5G solar light.

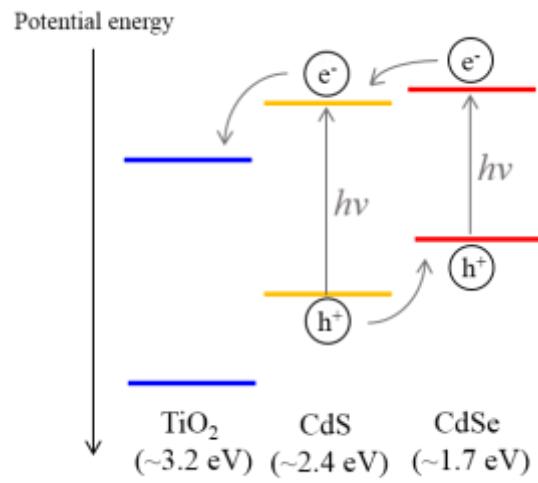


Fig. S3. Schematic diagram of the electron-hole transport in the $\text{CdSe}/\text{CdS}/\text{TiO}_2$ heterojunction structures.

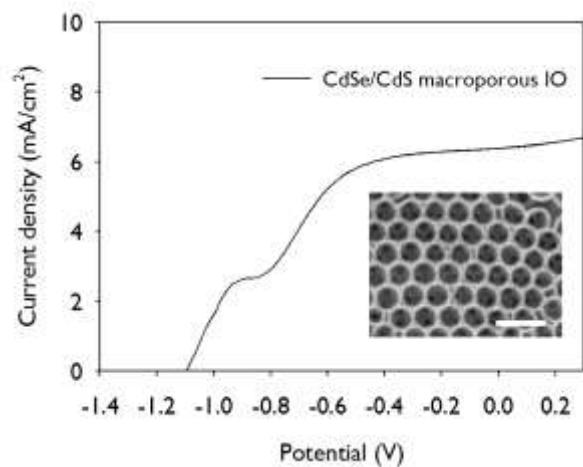


Fig. S4. (a) Current-voltage curves of CdSe/CdS macroporous IO TiO₂ film under 1 sun illumination (AM 1.5G). The pore diameter and thickness of the macroporous IO film (see the inset, scale bar: 500 nm) was approximately 200 nm and 6 μ m, respectively.

Table S1. PEC photocurrent density of various IO structures

| Component of inverse opal structure | Pore size | Photocurrent density (mA/cm ²) |
|--------------------------------------------------------|-----------|--------------------------------------------|
| graphene / Fe ₂ O ₃ ¹ | 780nm | 3.7 @0.5V vs. Ag/AgCl |
| Fe ₂ O ₃ ² | 810nm | 3.1 @0.15V vs. Ag/AgCl |
| CdS/TiO ₂ ³ | 270nm | 4.84 @0V vs. Ag/AgCl |
| ZnO nanobushes/CdS TiO ₂ ⁴ | 300nm | 6.2 @0V vs. Ag/AgCl |
| Au nanoparticles/TiO ₂ ⁵ | 350nm | 0.8 @0.5V vs. Ag/AgCl |

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Table S2. Photocurrent density, thickness and volumetric current density quantum-dot-sensitized metal oxide structures.

| Structure | Current density (mA/cm ²) | Thickness (μm) | Volumetric current density (mA/cm ² ·μm) |
|-------------------------------------------------------------------------|------------------------------------------|-------------------|--------------------------------------------------------|
| CdS-sensitized TiO ₂ inverse opal | 4.84 | 10 | 0.484 |
| CdSe-sensitized textured porous ZnO ⁶ | 4.3 | 6 | 0.52 |
| CdS/ZnO urchinlike hierarchical structure ⁷ | 12 | 2.5 | 4.8 |
| ZnO-CdSSe-core-shell nanowire arrays ⁸ | 6 | 10 | 0.6 |
| PbS/CdS/TiO ₂ heterostructure ⁹ | 6 | 12 | 0.5 |
| CdSe/CdS/ZnO 3D nanostructures ¹⁰ | 17.5 | 15 | 1.75 |
| WO ₃ /W:BiVO ₄ core/shell nanowires ¹¹ | 3.1 | 2.5 | 1.24 |
| CdS quantum dot sensitized Si/ZnO hierarchical structure ¹² | 0.9 | 70 | 0.012 |
| TiO ₂ nanotube arrays/Ag ₂ S ¹³ | 0.84 | 4.1 | 0.21 |
| WO ₃ /Mo doped BiVO ₄ bilayers ¹⁴ | 1.7 | 2.1 | 0.81 |
| This study (CdSe/CdS bilayer meso inverse opal TiO ₂) | 13.67 | 7 | 1.95 |

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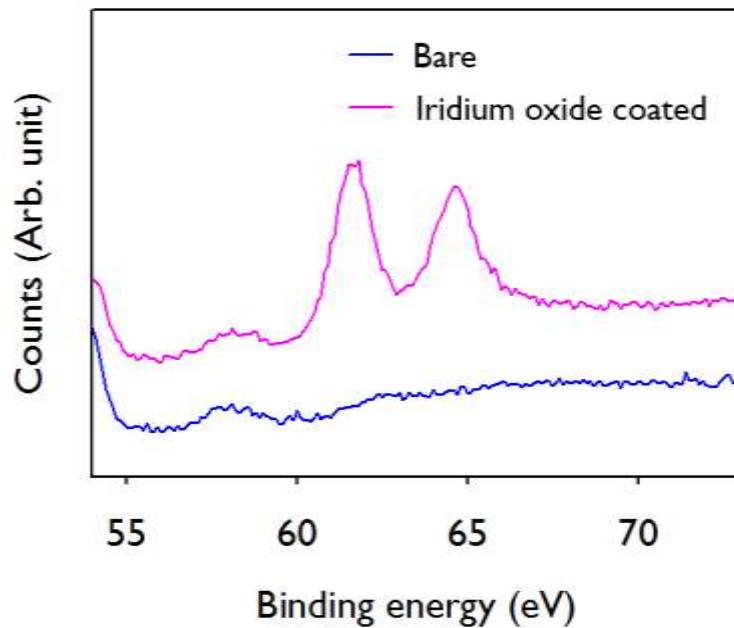


Fig. S5. Iridium XPS spectra of CdSe/CdS/TiO₂ and iridium oxide particle-coated CdSe/CdS/TiO₂. The strong double peaks are originated from Ir 4f_{7/2}, Ir 4f_{5/2}, and Ir 5p_{1/2}.¹⁵ The quantity of Ir was 3 at.%.